# CM1263-02SE

# Low Capacitance ESD Protection for High-Speed Serial Interfaces

#### **Features**

- 2 Channels of ESD Protection
- 0.85 pF Loading Capacitance per Channel Typical
- Provides ESD Protection to IEC61000-4-2 Level 4:
  - ±8 kV Contact Discharge
  - ±15 kV Air Discharge
- 5-Pin SOT-553 Package
- These Devices are Pb-Free and are RoHS Compliant

#### **Applications**

- LCD and Camera Data Lines in Wireless Handsets that Use High-speed Serial Interfaces such as MDDI, MIPI, MVI and MPL
- I/O Port Protection for Mobile Handsets, Notebook Computers, PDAs, etc.
- Wireless Handsets
- Handheld PCs/PDAs
- LCD and Camera Modules



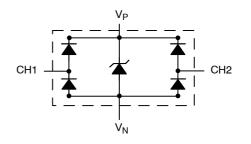
# ON Semiconductor®

http://onsemi.com



SOT-553 SE SUFFIX CASE 463B

#### **BLOCK DIAGRAM**



#### **MARKING DIAGRAM**



L63 = Specific Device Code M = Date Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
CM1263-02SE	SOT-553 (Pb-Free)	5000/Tape & Reel

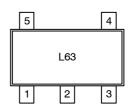
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# CM1263-02SE

**Table 1. PIN DESCRIPTIONS** 

5-Pin, SOT-553 Package		
Pin	Description	
1	V <sub>P</sub>	
2	V <sub>N</sub>	
3	NC	
4	(CH1) ESD Channel #1	
5	(CH2) ESD Channel #2	

### **PACKAGE / PINOUT DIAGRAM**



## **SPECIFICATIONS**

**Table 2. ABSOLUTE MAXIMUM RATINGS** 

Parameter	Rating	Units
Operating Supply Voltage (V <sub>P</sub> – V <sub>N</sub> )	6.0	V
Operating Temperature Range	-40 to +85	°C
Storage Temperature Range	-65 to +150	°C
DC Voltage at any channel input	$(V_N - 0.5)$ to $(V_P + 0.5)$	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## CM1263-02SE

Table 3. ELECTRICAL OPERATING CHARACTERISTICS (Note 1)

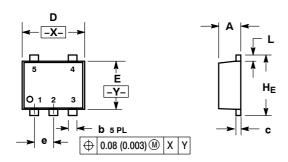
Symbol	Parameter	Conditions	Min	Тур	Max	Units
V <sub>P</sub>	Operating Supply Voltage (V <sub>P</sub> – V <sub>N</sub> )			3.3	5.5	V
l <sub>P</sub>	Operating Supply Current	$(V_P - V_N) = 3.3 \text{ V}$			8.0	μΑ
V <sub>F</sub>	Diode Forward Voltage Top Diode Bottom Diode	I <sub>F</sub> = 8 mA; T <sub>A</sub> = 25°C	0.60 0.60	0.80 0.80	0.95 0.95	٧
I <sub>LEAK</sub>	Channel Leakage Current	$T_A = 25^{\circ}C; V_P = 5 \text{ V}, V_N = 0 \text{ V}, V_{TEST} = 0 \text{ to } 5 \text{ V}$		0.1	1.0	μΑ
C <sub>IN</sub>	Channel Input Capacitance	At 1 MHz, V <sub>P</sub> = 3.3 V, V <sub>N</sub> = 0 V, V <sub>IN</sub> = 1.65 V		0.85	1.2	pF
$\Delta C_{IN}$	Channel Input Capacitance Matching	At 1 MHz, V <sub>P</sub> = 3.3 V, V <sub>N</sub> = 0 V, V <sub>IN</sub> = 1.65 V		0.02		pF
V <sub>ESD</sub>	ESD Protection Peak Discharge Voltage at any channel input, in system: a) Contact Discharge per IEC 61000-4-2 standard b) Air Discharge per IEC 61000-4-2 standard	T <sub>A</sub> = 25°C; (Notes 2 and 3) T <sub>A</sub> = 25°C; (Note 3)	±8 ±15			kV
V <sub>CL</sub>	Channel Clamp Voltage Positive Transients Negative Transients	$T_A = 25^{\circ}C$ , $I_{PP} = 1$ A, $t_P = 8/20 \ \mu S$ (Note 3)		+9.96 -1.6		V
R <sub>DYN</sub>	Dynamic Resistance Positive Transients Negative Transients	$\begin{split} I_{PP} = 1 & \text{A, t}_P = 8/20 \ \mu\text{S} \\ \text{Any I/O pin to Ground;} \\ \text{(Note 3)} \end{split}$		0.96 0.5		Ω

<sup>1.</sup> All parameters specified at  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  unless otherwise noted.
2. Standard IEC 61000–4–2 with  $C_{Discharge} = 150\text{pF}$ ,  $R_{Discharge} = 330~\Omega$ ,  $V_P = 3.3~V$ ,  $V_N$  grounded.
3. These measurements performed with no external capacitor on  $V_P$  ( $V_P$  floating).

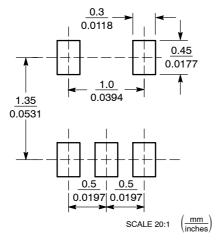


SOT-553, 5 LEAD CASE 463B **ISSUE C** 

**DATE 20 MAR 2013** 



#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETERS

  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS: MINIMUM LEAD THICKNESS IS THE MINIMUM
  THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
O	0.08	0.13	0.18	0.003	0.005	0.007
D	1.55	1.60	1.65	0.061	0.063	0.065
Е	1.15	1.20	1.25	0.045	0.047	0.049
е	0.50 BSC				0.020 BSC	
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.55	1.60	1 65	0.061	0.063	0.065

#### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. ANODE
2. EMITTER	2. COMMON ANODE	2. N/C	2. DRAIN 1/2	2. EMITTER
3. BASE	<ol><li>CATHODE 2</li></ol>	<ol><li>ANODE 2</li></ol>	<ol><li>SOURCE 1</li></ol>	3. BASE
4. COLLECTOR	<ol><li>CATHODE 3</li></ol>	<ol><li>CATHODE 2</li></ol>	4. GATE 1	<ol><li>COLLECTOR</li></ol>
<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE 4</li></ol>	<ol><li>CATHODE 1</li></ol>	5. GATE 2	<ol><li>CATHODE</li></ol>
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	
3. EMITTER 1	3. BASE	3. N/C	3. ANODE	
4. COLLECTOR 1	<ol><li>COLLECTOR</li></ol>	4. BASE	4. ANODE	
<ol><li>COLLECTOR 2/BASE 1</li></ol>	<ol><li>COLLECTOR</li></ol>	5. EMITTER	5. ANODE	

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<b>DOCUMENT</b>	NUMBER:
98AON11127	'D

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ISSUE	REVISION	DATE
Α	ADDED STYLES 3-9. REQ. BY D. BARLOW	11 NOV 2003
В	ADDED NOMINAL VALUES AND UPDATED GENERIC MARKING DIAGRAM. REQ. BY HONG XIAO	27 MAY 2005
С	UPDATED DIMENSIONS D, E, AND HE. REQ. BY J. LETTERMAN.	20 MAR 2013

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